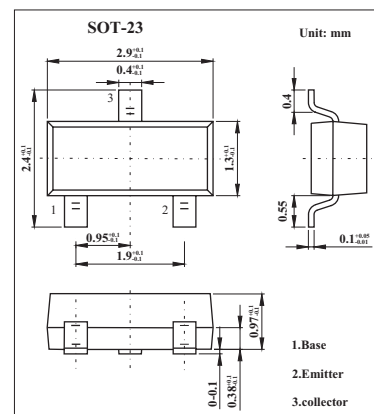


NPN Transistors

KST9013

■ Features

- Excellent h_{FE} linearity
- Collector Current : $I_C=0.5A$



■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	40	V
Collector - Emitter Voltage	V_{CE0}	25	V
Emitter - Base Voltage	V_{EB0}	5	V
Collector Current - Continuous	I_C	500	mA
Collector Power Dissipation	P_C	300	mW
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature	T_{stg}	-55 to 150	$^\circ C$

■ Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector - base breakdown voltage	V_{CB0}	$I_C = 100 \mu A$, $I_E = 0$	40			V
Collector - emitter breakdown voltage	V_{CE0}	$I_C = 0.1mA$, $I_B = 0$	25			V
Emitter - base breakdown voltage	V_{EB0}	$I_E = 100 \mu A$, $I_C = 0$	5			V
Collector cut - off current	I_{CBO}	$V_{CB} = 40V$, $I_E = 0$			0.1	μA
Collector cut - off current	I_{CEO}	$V_{CE} = 20V$, $I_B = 0$			0.1	μA
Emitter cut - off current	I_{EBO}	$V_{EB} = 5V$, $I_C = 0$			0.1	μA
DC current gain	h_{FE}	$V_{CE} = 1V$, $I_C = 50mA$	120		400	
		$V_{CE} = 1V$, $I_C = 500mA$	40			
Collector - emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500mA$, $I_B = 50mA$			0.6	V
Base - emitter saturation voltage	$V_{BE(sat)}$	$I_C = 500mA$, $I_B = 50mA$			1.2	V
Transition frequency	f_T	$V_{CE} = 6V$, $I_C = 20mA$, $f = 30MHz$	150			MHz

■ h_{FE} Classification

Marking	J3		
Rank	L	H	J
h_{FE}	120 to 200	200 to 350	300 to 400

KST9013

■ Typical Characteristics

